

# AM27S29, '29A, '29SA

4,096-Bit (512x8) Bipolar PROM

The AM27S29 (512-words by 8-bits) is a Schottky TTL Programmable Read-Only Memory (PROM).

This device has three-state outputs, compatible with low-power Schottky bus standards capable of satisfying the requirements of a variety of microprogrammable controls, mapping functions, code conversion, or logic replacement. Easy word depth expansion is facilitated by an active LOW ( $\overline{G}$ ) output enable.

## Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

## **Quality Overview**

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
  - Class Q Military
  - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
  - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

# Am27S29/Am27S29A/Am27S29SA



4,096-Bit (512x8) Bipolar PROM

### DISTINCTIVE CHARACTERISTICS

- · High Speed
- Highly reliable, ultra-fast programming Platinum-Silicide tuses
- High programming yield

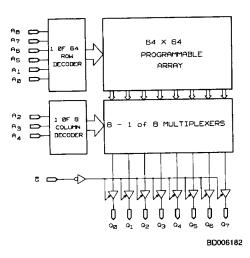
- Low-current PNP inputs
- · High-current open-collector and three-state outputs
- Fast chip select

#### **GENERAL DESCRIPTION**

The Am27S29 (512-words by 8-bits) is a Schottky TTL Programmable Read-Only Memory (PROM).

This device has three-state outputs, compatible with lowpower Schottky bus standards capable of satisfying the requirements of a variety of microprogrammable controls, mapping functions, code conversion, or logic replacement. Easy word depth expansion is facilitated by an active LOW  $(\overline{G})$  output enable.

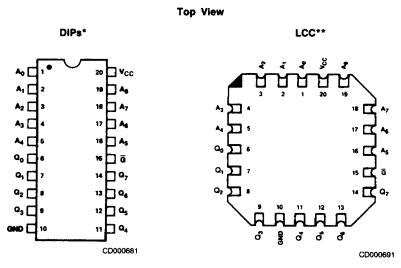
### FUNCTIONAL BLOCK DIAGRAM



PRODUCT SELECTOR GUIDE

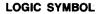
Three-State Part Number	Am27	S29SA	Am27	/S29A	Am27S29		
Address Access Time	30 ns	40 ns	35 ns	45 ns	55 ns	70 ns	
Operating Range	с	м	с	м	С	м	

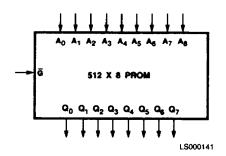
#### CONNECTION DIAGRAMS



\*Also available in a 20-pin Flatpack. Pinout identical to DIPs. \*\*Also available in a 20-pin PLCC. Pinout identical to LCC.

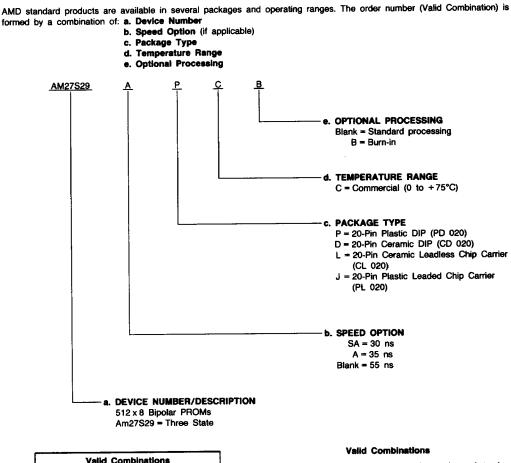
Note: Pin 1 is marked for orientation.





#### ORDERING INFORMATION

#### **Standard Products**

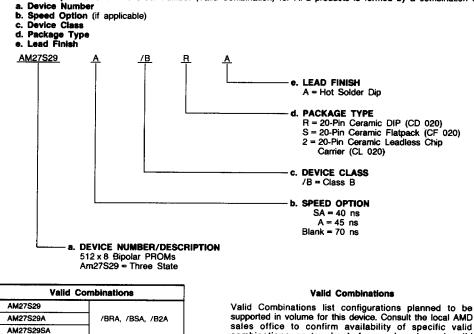


Valid Combinations								
AM27S29								
AM27S29A	PC, PCB, DC, DCB, LC, LCB, JC, JCB							
AM27S29SA	10, 200, 00, 000							

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific combinations, to check on newly released valid combinations, and to obtain additional data on AMD's standard military grade products.

#### ORDERING INFORMATION **APL Products**

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. CPL (Controlled Products List) products are processed in accordance with MIL-STD-883C, but are inherently non-compliant because of package, solderability, or surface treatment exceptions to those specifications. The order number (Valid Combination) for APL products is formed by a combination of:



sales office to confirm availability of specific valid combinations or to check for newly released valid combinations.

#### **Group A Tests**

Group A Tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

#### **MILITARY BURN-IN**

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

#### PIN DESCRIPTION

#### A<sub>0</sub> – A<sub>8</sub> Address (Inputs)

The 9-bit field presented at the address inputs selects one of 512 memory locations to be read from.

#### Q<sub>0</sub> - Q<sub>7</sub> **Data Output Port**

The outputs whose state represents the data read from the selected memory locations.

#### ā. Output Enable (Input)

Provides direct control of the Q-output buffers. Outputs disabled forces all three-state outputs to a floating or highimpedance state.

#### Enable = G

Disable = G

#### V<sub>CC</sub> Device Power Supply Pin

The most positive of the logic power supply pins.

#### GND Device Power Supply Pin

The most negative of the logic power supply pins.

#### ABSOLUTE MAXIMUM RATINGS

Storage Temperature 65 to + 150°C
Ambient Temperature with
Power Applied 55 to + 125°C
Supply Voltage 0.5 V to +7.0 V
DC Voltage Applied to Outputs
(Except During Programming) 0.5 V to + V <sub>CC</sub> Max.
DC Voltage Applied to Outputs
During Programming 21 V
Output Current into Outputs During
Programming (Max. Duration of 1 sec) 250 mA
DC Input Voltage 0.5 V to +5.5 V
DC Input Current 30 mA to +5 mA
Stresses above those listed under ABSOLUTE MAXIMUM

RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

## **OPERATING RANGES**

Commercial (C) Devices Ambient Temperature (T <sub>A</sub> )0 to +75°C Supply Voltage (V <sub>CC</sub> )+4.75 V to +5.25 V	
Military (M) Devices*	
Case Temperature (T <sub>C</sub> ) 55 to + 125°C	
Supply Voltage (V <sub>CC</sub> ) +4.5 V to +5.5 V	

Operating ranges define those limits between which the functionality of the device is guaranteed.

\*Military product 100% tested at T<sub>C</sub> = + 25°C, + 125°C, and -55°C.

DC CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Grou	ρA,
Subaroups 1, 2, 3 are tested unless otherwise noted)	

Parameter Symbol	Parameter Description		Min.	Тур.	Max.	Unit		
VOH (Note 1)	Output HIGH Voltage	V <sub>CC</sub> = Min., I <sub>OH</sub> V <sub>IN</sub> = V <sub>IH</sub> or V <sub>I</sub>		2.4			v	
VOL	Output LOW Voltage	V <sub>CC</sub> = Min., l <sub>OL</sub> V <sub>IN</sub> = V <sub>IH</sub> or V <sub>I</sub>				0.50	v	
VIH	Input HIGH Level	Guaranteed inp voltage for all i		2.0			v	
VIL	Input LOW Level	Guaranteed inp voltage for all i				0.8	v	
կլ	Input LOW Current	V <sub>CC</sub> = Max., V <sub>II</sub>	N = 0.45 V			-0.250	mA	
he	Input HIGH Current	V <sub>CC</sub> = Max., V <sub>II</sub>	N = 2.7 V			25	μA	
ISC (Note 1)	Output Short-Circuit Current	V <sub>CC</sub> = Max., V <sub>C</sub>	UT = 0.0 V (No	-20		-90	mA	
	Power Supply Current	All inputs = GN V <sub>CC</sub> = Max.	D			160	m A	
Vi	Input Clamp Voltage	V <sub>CC</sub> = Min., I <sub>IN</sub>	= - 18 mA				- 1.2	V
		Vcc = Max.		Vo = Vcc			40	μΑ
ICEX	Output Leakage Current	VG = 2.4 V	(Note 1)	VOUT = 0.4 V			-40	
CIN	Input Capacitance	V <sub>IN</sub> = 2.0 V @ T <sub>A</sub> = 25°C	f = 1 MHz (Not	e 4) V <sub>CC</sub> = 5 V;		4		ρF
COUT	Output Capacitance	V <sub>OUT</sub> = 2.0 V ( T <sub>A</sub> = 25°C	@r f=1MHz(N	ote 4)V <sub>CC</sub> = 5 V;		8		

1. This applies to three-state devices only. Notes:

2. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.

3. Not more than one output should be shorted at a time. Duration of the short circuit should not be more than one second. 4. These parameters are not 100% tested, but are periodically evaluated at initial characterization and at any time the design is modified

where capacitance may be affected.

SWITCHING CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted\*)

			"SA" Version			"A" Version			Standard Version						
	1		COM'L		L MIL		COM'L		MIL		COM'L		MIL		
No.	Parameter Symbol	Parameter Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
1	TAVQV	Address Valid to Output Valid Access Time		30		40		35		45		55		70	ns.
2	TGVQZ	Delay from Output Enable Valid to Output Hi-Z		20		25		20		25		25		30	ns
з	TGVQV	Delay from Output Enable Valid to Output Valid		20		25		20		25		25		30	ns

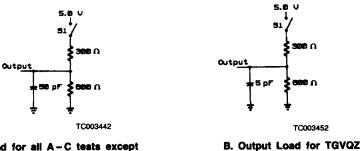
See also Switching Test Circuits.

Notes: 1. Tests are performed with input transition time of 5 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V using test load in Figure A. 2. TGVQZ is measured at steady state HIGH output voltage -0.5 V and steady state LOW output voltage +0.5 V ouput levels using

the test load in Figure B.

\*Subgroups 7 and 8 apply to functional tests.

#### SWITCHING TEST CIRCUITS



A. Output Load for all A-C tests except TGVQZ

Notes: 1. All device test loads should be located within 2" of device output pin.

- 2. St is open for Output Data HIGH to Hi-Z and Hi-Z to Output Data HIGH tests.
  - S1 is closed for all other AC tests.
- 3. Load capacitance includes all stray and fixture capacitance.

#### SWITCHING WAVEFORMS

